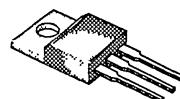


PRODUCT SUMMARY

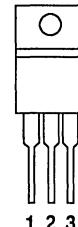
| $V_{(BR)DSS}$ (V) | $r_{DS(ON)}$ (Ω) | I_D (A) | PACKAGE |
|----------------------|------------------------------|--------------|----------|
| 40 | 3 | 1.46 | TO-220SD |

Performance Curves: VNDQ06 (See Section 7)

TO-220SD



TOP VIEW



- 1 SOURCE
- 2 GATE
- 3 & TAB - DRAIN

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETERS/TEST CONDITIONS | SYMBOL | VN46AFD | UNITS |
|--|----------------|------------|------------------|
| Drain-Source Voltage | V_{DS} | 40 | V |
| Gate-Source Voltage | V_{GS} | ± 30 | |
| Continuous Drain Current | I_D | 1.46 | A |
| | | 0.92 | |
| Pulsed Drain Current ¹ | I_{DM} | 3 | |
| Power Dissipation | P_D | 15 | W |
| | | 6 | |
| Operating Junction and Storage Temperature | T_J, T_{stg} | -55 to 150 | $^\circ\text{C}$ |
| Lead Temperature (1/16" from case for 10 seconds) | T_L | 300 | |

6

THERMAL RESISTANCE

| THERMAL RESISTANCE | SYMBOL | VN46AFD | UNITS |
|--------------------|------------|---------|---------------------------|
| Junction-to-Case | R_{thJC} | 8.3 | $^\circ\text{C}/\text{W}$ |

¹Pulse width limited by maximum junction temperature

| ELECTRICAL CHARACTERISTICS ¹ | | | LIMITS | | | |
|---|---------------------|--|------------------|---------|-----------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | TYP ² | VN46AFD | | UNIT |
| | | | | MIN | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0 \text{ V}$, $I_D = 10 \mu\text{A}$ | 70 | 40 | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}$, $I_D = 1 \text{ mA}$ | 1.5 | 0.8 | 2.5 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 15 \text{ V}$ | ± 1 | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 40 \text{ V}$, $V_{GS} = 0 \text{ V}$ | 0.05 | | 10 | μA |
| | | $V_{DS} = 32 \text{ V}$, $V_{GS} = 0 \text{ V}$, $T_C = 125^\circ\text{C}$ | 0.3 | | 500 | |
| On-State Drain Current ³ | $I_{D(\text{ON})}$ | $V_{DS} = 10 \text{ V}$, $V_{GS} = 10 \text{ V}$ | 1.8 | 1 | | A |
| Drain-Source On-Resistance ³ | $r_{DS(\text{ON})}$ | $V_{GS} = 5 \text{ V}$, $I_D = 0.3 \text{ A}$ | 1.8 | | 5 | Ω |
| | | $V_{GS} = 10 \text{ V}$ $I_D = 1 \text{ A}$ | 1.3 | | 3 | |
| | | $T_C = 125^\circ\text{C}$ | 2.6 | | 6 | |
| Forward Transconductance ³ | g_{FS} | $V_{DS} = 10 \text{ V}$, $I_D = 0.5 \text{ A}$ | 350 | 170 | | mS |
| Common Source Output Conductance ³ | g_{os} | $V_{DS} = 10 \text{ V}$, $I_D = 0.1 \text{ A}$ | 1100 | | | μs |
| DYNAMIC | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 25 \text{ V}$ $V_{GS} = 0 \text{ V}$ $f = 1 \text{ MHz}$ | 35 | | 50 | pF |
| Output Capacitance | C_{oss} | | 25 | | 65 | |
| Reverse Transfer Capacitance | C_{rss} | | 5 | | 10 | |
| SWITCHING | | | | | | |
| Turn-On Time | t_{ON} | $V_{DD} = 25 \text{ V}$, $R_L = 23 \Omega$, $I_D = 1 \text{ A}$, $V_{GEN} = 10 \text{ V}$ $R_G = 25 \Omega$ (Switching time is essentially independent of operating temperature) | 8 | | 15 | ns |
| Turn-Off Time | t_{OFF} | | 9.5 | | 15 | |

NOTES: 1. $T_C = 25^\circ\text{C}$ unless otherwise noted.

2. For design aid only, not subject to production testing.

3. Pulse test; $PW = 300 \mu\text{s}$, duty cycle $\leq 2\%$.